

900V Silicon Carbide Schottky Diode

DESCRIPTION :

- Negligible reverse recovery
- High Speed Switching
- Positive temperature Coefficient
- Temperature Independent Switching
- RoHS Compliant

| | |
|-----------|---------------------------|
| V_{RRM} | 900V |
| I_F | 20A ($T_C=157^\circ C$) |
| Q_C | 106nC |

TYPICAL APPLICATIONS :

- Switch mode power supplies
- Solar inverters
- Data Center
- Uninterruptible power supplies (UPS)



TO-247AC

MAXIMUM RATINGS (at $T_C = 25^\circ C$, unless otherwise specified)

| Characteristic | Condition | Symbol | Value | Unit |
|---------------------------------------|---|---------------|------------------|------------|
| Repetitive Peak Reverse Voltage | | V_{RRM} | 900 | V |
| Continuous Forward Current | $T_C=25^\circ C$ $T_C=135^\circ C$ $T_C=157^\circ C$ | I_F | 64 31 20 | A |
| Non-Repetitive Forward Surge Current | $T_C=25^\circ C$, $t_P=10ms$, Half sine pulse $T_C=110^\circ C$, $t_P=10ms$, Half sine pulse | I_{FSM} | 125 98 | A |
| Repetitive Peak Forward Surge Current | $T_C=25^\circ C$, $t_P=10ms$, Half sine pulse $T_C=25^\circ C$, $t_P=10ms$, Half sine pulse | I_{FRM} | 110 95 | A |
| i^2t value | $T_C=25^\circ C$, $t_P=10ms$ $T_C=110^\circ C$, $t_P=10ms$ | $\int i^2 dt$ | 72 48 | $A^2 S$ |
| Power dissipation | $T_C=25^\circ C$ $T_C=110^\circ C$ $T_C=150^\circ C$ | P_{tot} | 361 156 60 | W |
| Operation Junction temperature | | T_j | -55~+175 | $^\circ C$ |
| Storage temperature | | T_{STG} | -55~+175 | $^\circ C$ |

THERMAL CHARACTERISTICS

| Characteristic | Condition | Symbol | Typical | Unit |
|--|-----------|---------------|---------|------|
| Thermal resistance, junction - case | | $R_{th(j-C)}$ | 0.415 | °C/W |

ELECTRICAL CHARATERISTICS (at $T_C = 25$ °C, unless otherwise specified)

| Characteristic | Symbol | Min. | Typ. | Max. | Unit |
|--|----------|------|------------------------------|------|------|
| DC Blocking Voltage | V_{DC} | 900 | | | V |
| Forward Voltage IF = 10A IF = 20A, $T_c = 25$ °C IF = 20A, $T_c = 125$ °C IF = 20A, $T_c = 175$ °C | V_F | | 1.16 1.39 1.69 1.89 | 1.6 | V |
| Reverse Current $VR = 900V, T_c = 25$ °C $VR = 900V, T_c = 125$ °C $VR = 900V, T_c = 175$ °C | I_R | | 4 10 20 | 200 | uA |
| Total Capacitive Charge $VR = 600V$ | Q_C | | 106 | | nC |
| Total capacitance $VR = 1V, f = 1MHz$ $VR = 300V, f = 1MHz$ $VR = 600V, f = 1MHz$ | C | | 1362 126 91 | | pF |
| Capacitance Stored Energy $VR = 600 V$ | E_C | | 22.5 | | uJ |

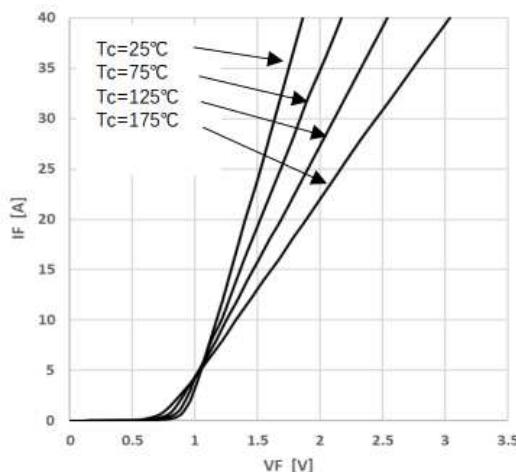


Figure 1. Forward characteristics

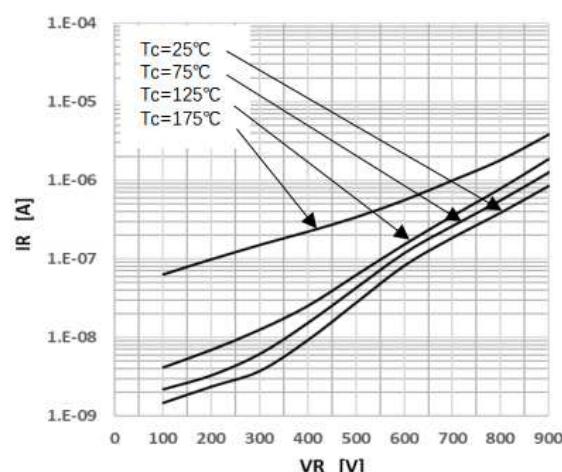


Figure 2. Reverse characteristics

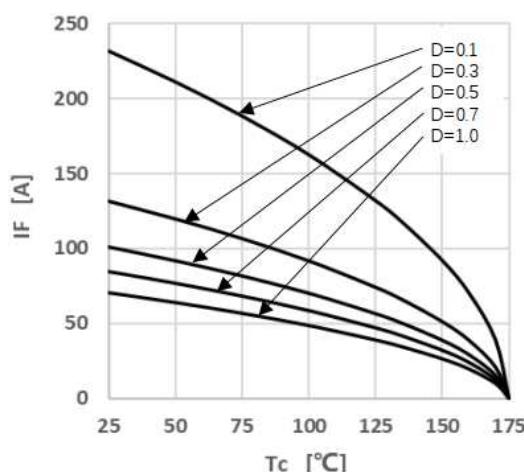


Figure 3. Peak Forward Current Derating

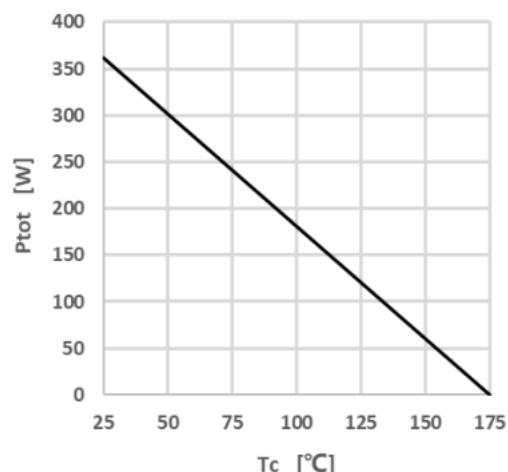


Figure 4. Power Dissipation

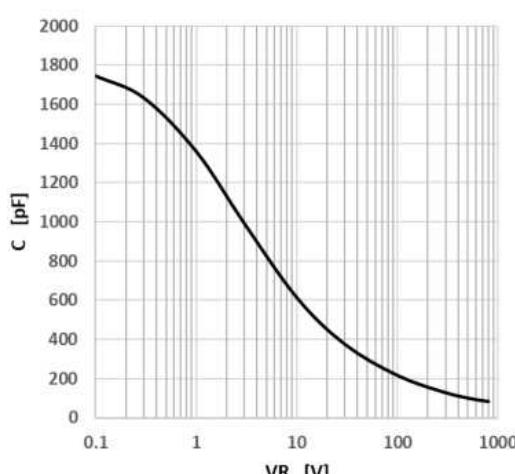


Figure 5. Capacitance vs. Reverse Voltage

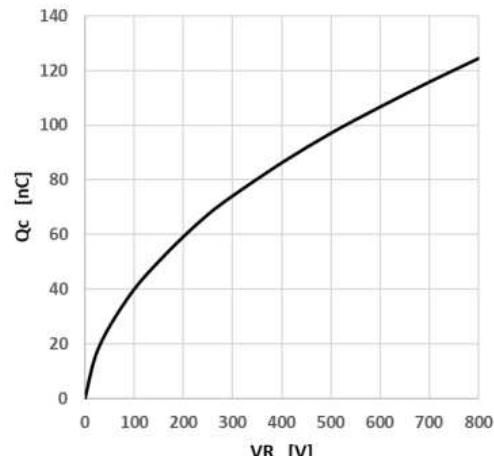


Figure 6. Capacitance Charge vs. Reverse Voltage

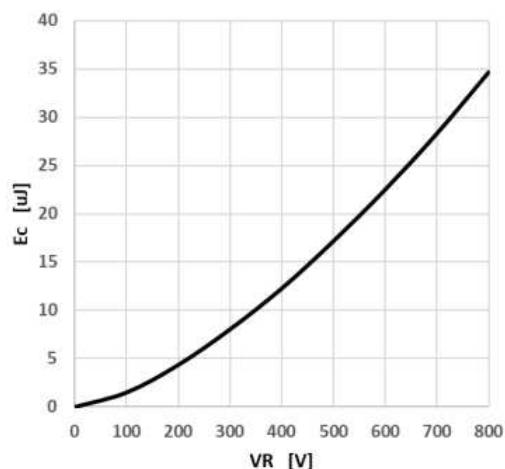


Figure 7. Capacitance Stored Energy

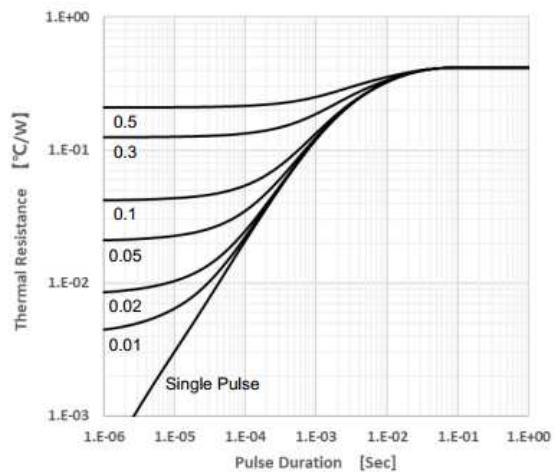
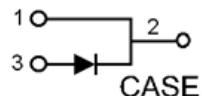
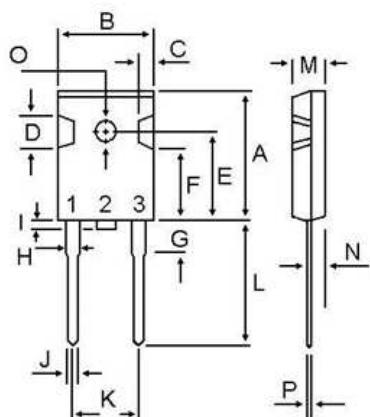


Figure 8. Transient Thermal Impedance

- Circuit diagram



- TO-247AC Package outlines : Dimensions in (mm)



| DIM | MILLIMETERS | |
|-----|-------------|-------|
| | MIN | MAX |
| A | 20.63 | 22.38 |
| B | 15.38 | 16.20 |
| C | 1.90 | 2.70 |
| D | 5.10 | 6.10 |
| E | 14.81 | 15.22 |
| F | 11.72 | 12.84 |
| G | 3.75 | 4.35 |
| H | 1.82 | 2.46 |
| I | --- | 1.25 |
| J | 0.89 | 1.53 |
| K | 10.52 | 11.32 |
| L | 18.50 | 21.50 |
| M | 4.68 | 5.36 |
| N | 2.40 | 2.80 |
| O | 3.25 | 3.65 |
| P | 0.55 | 0.70 |

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